

Fig.1
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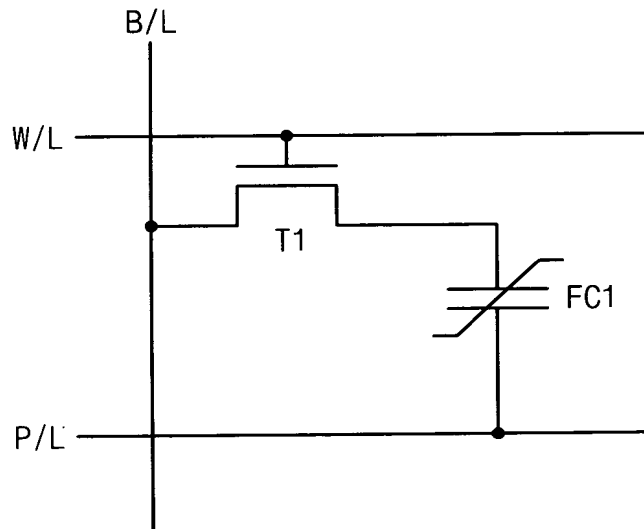


Fig.2
<Prior Art>

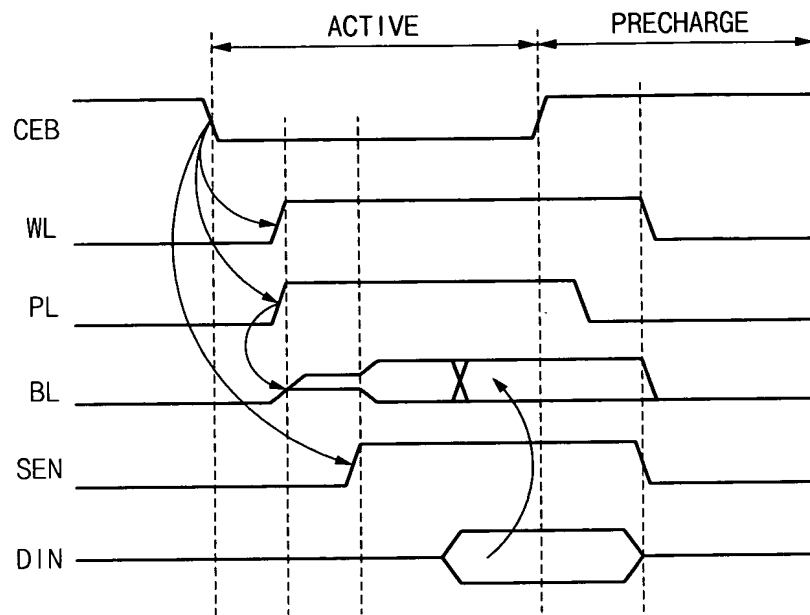


Fig.3a
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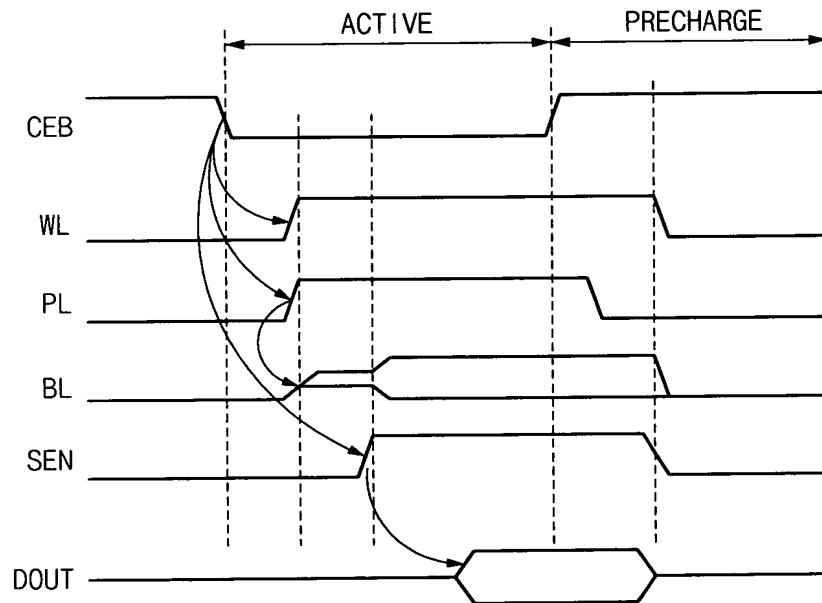


Fig.3b
<Prior Art>

Fig. 4

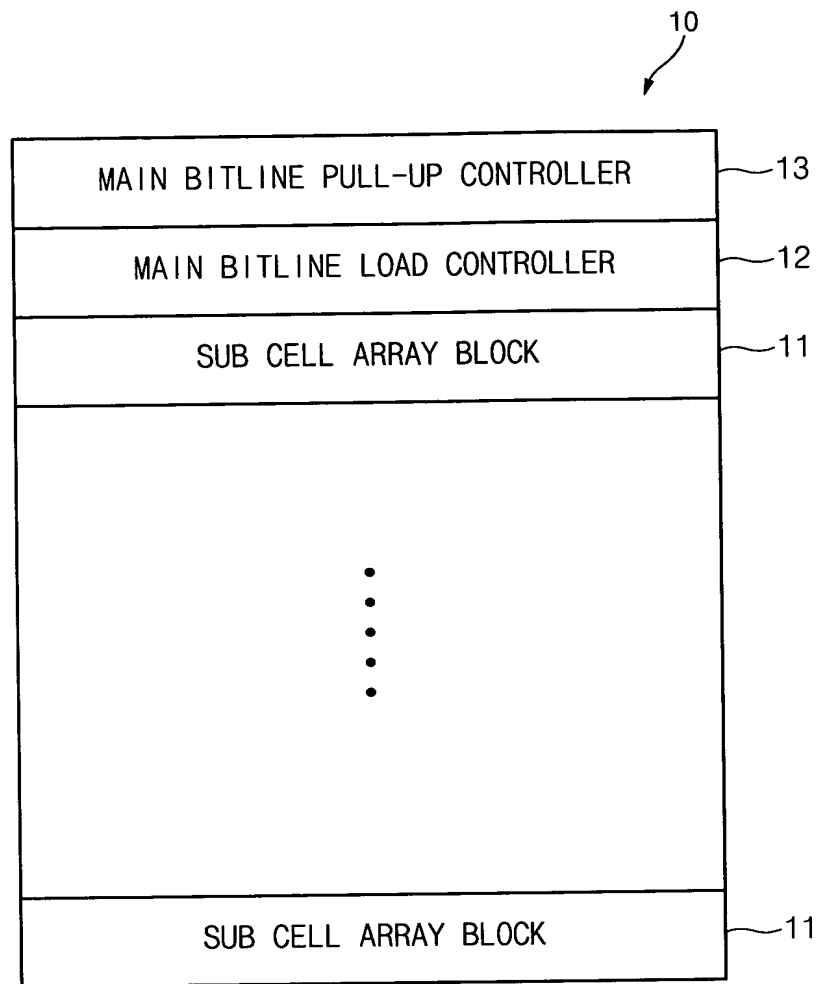


Fig.5

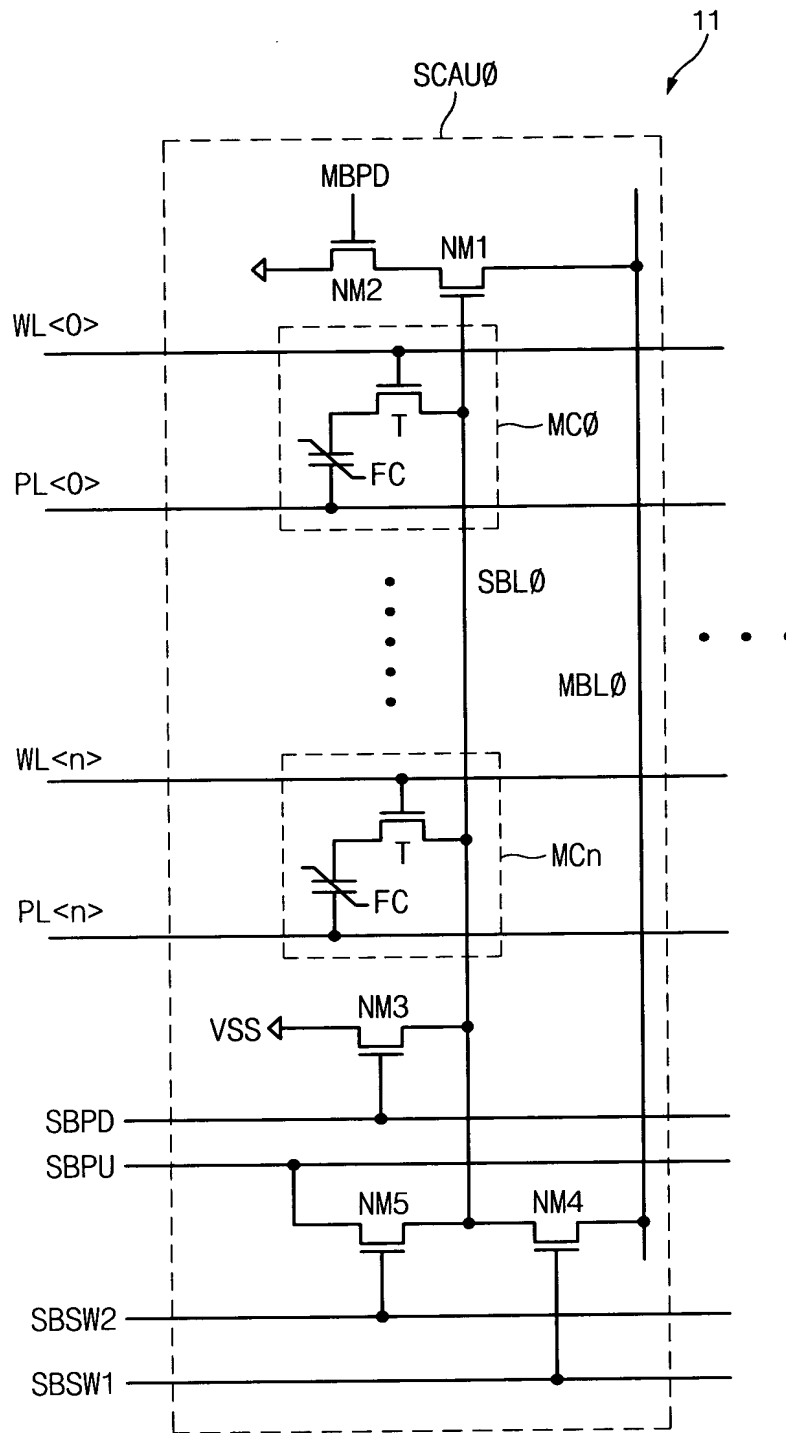


Fig.6

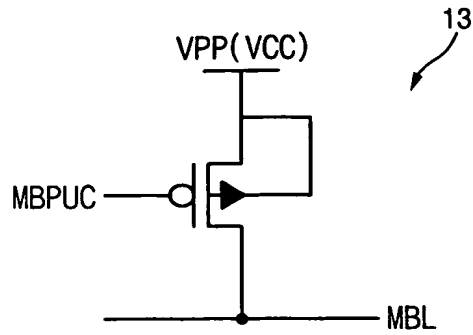


Fig.7

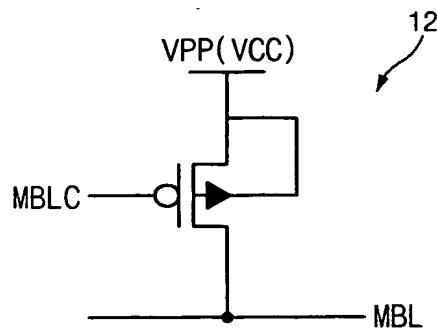


Fig.8

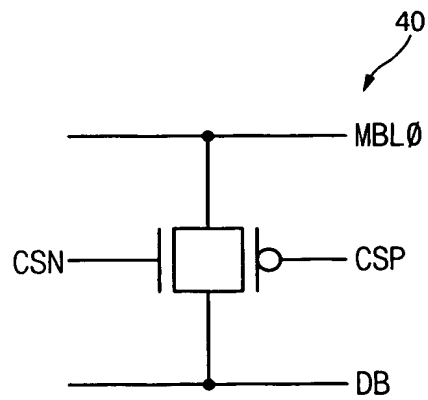


Fig.9

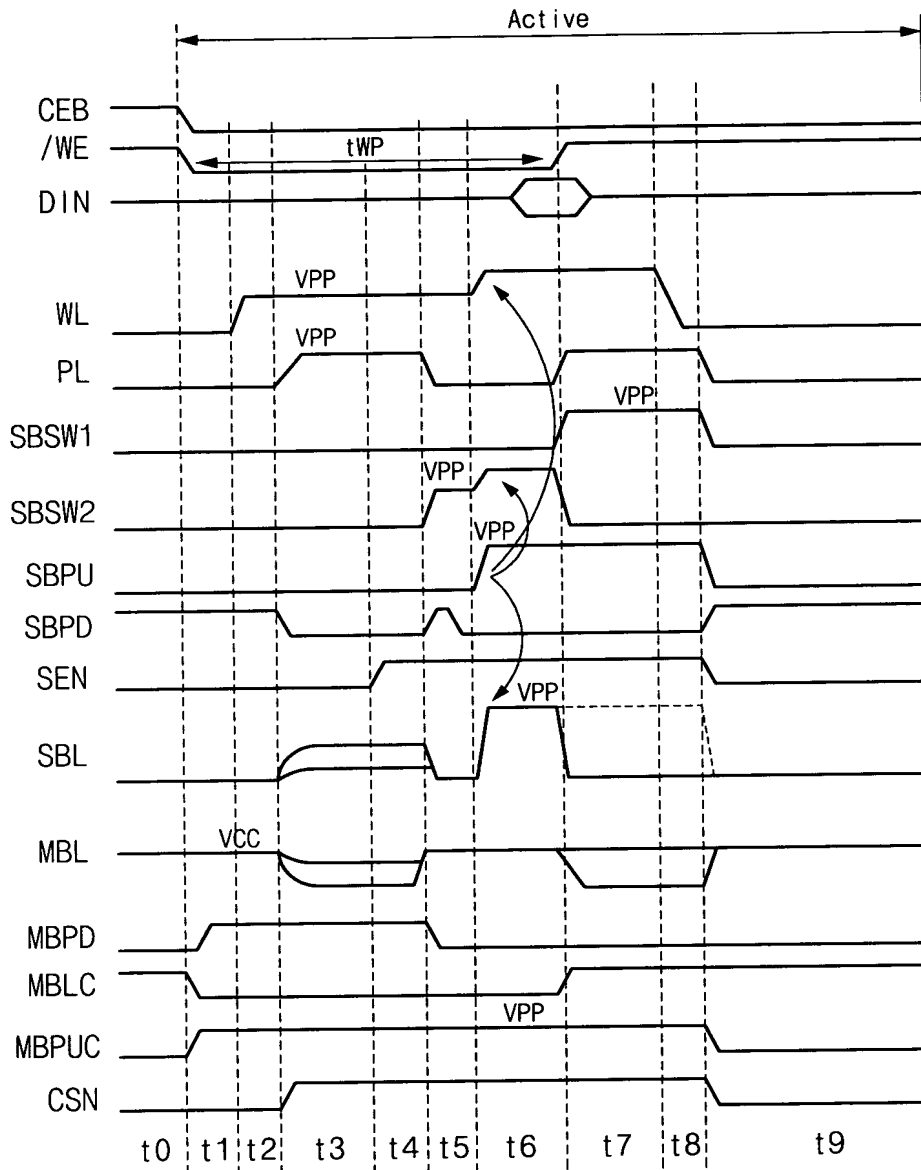


Fig.10

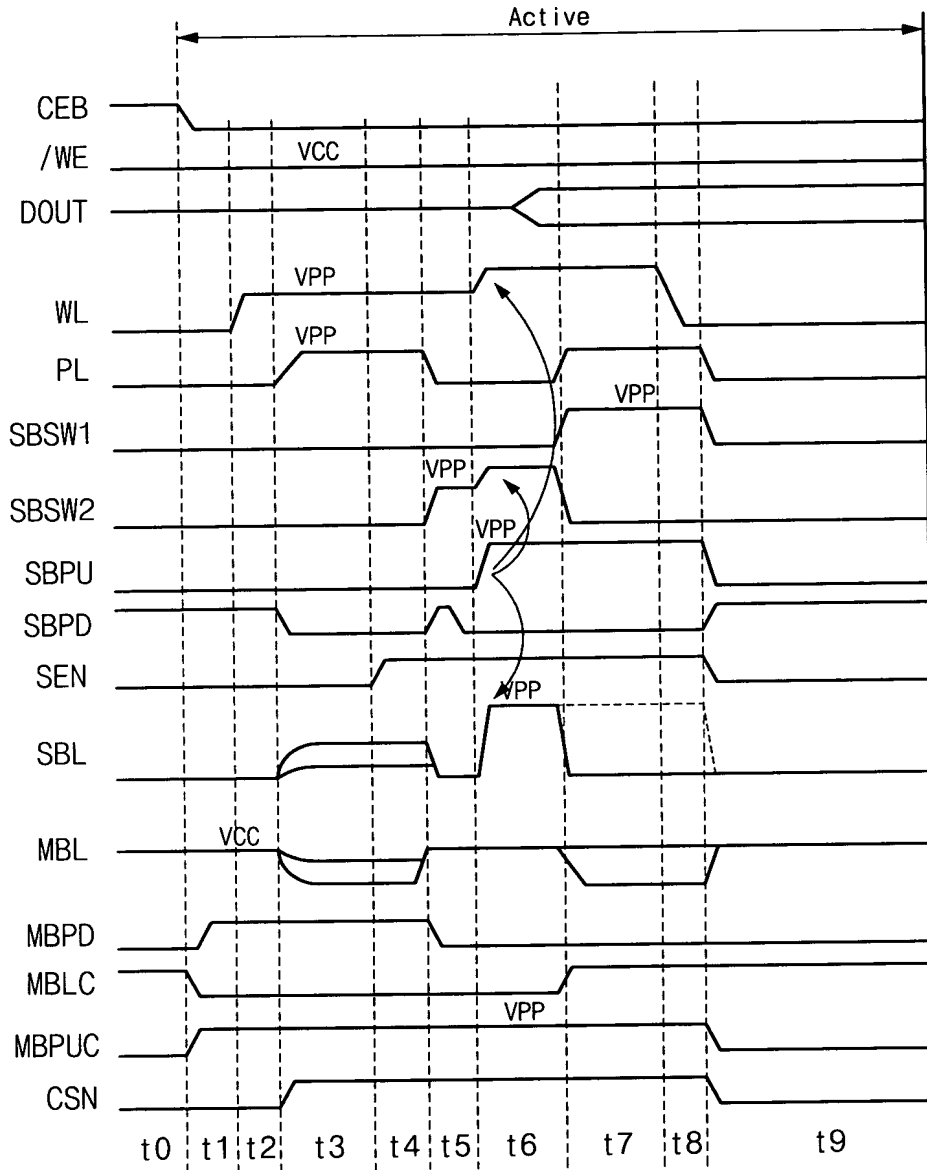


Fig.11

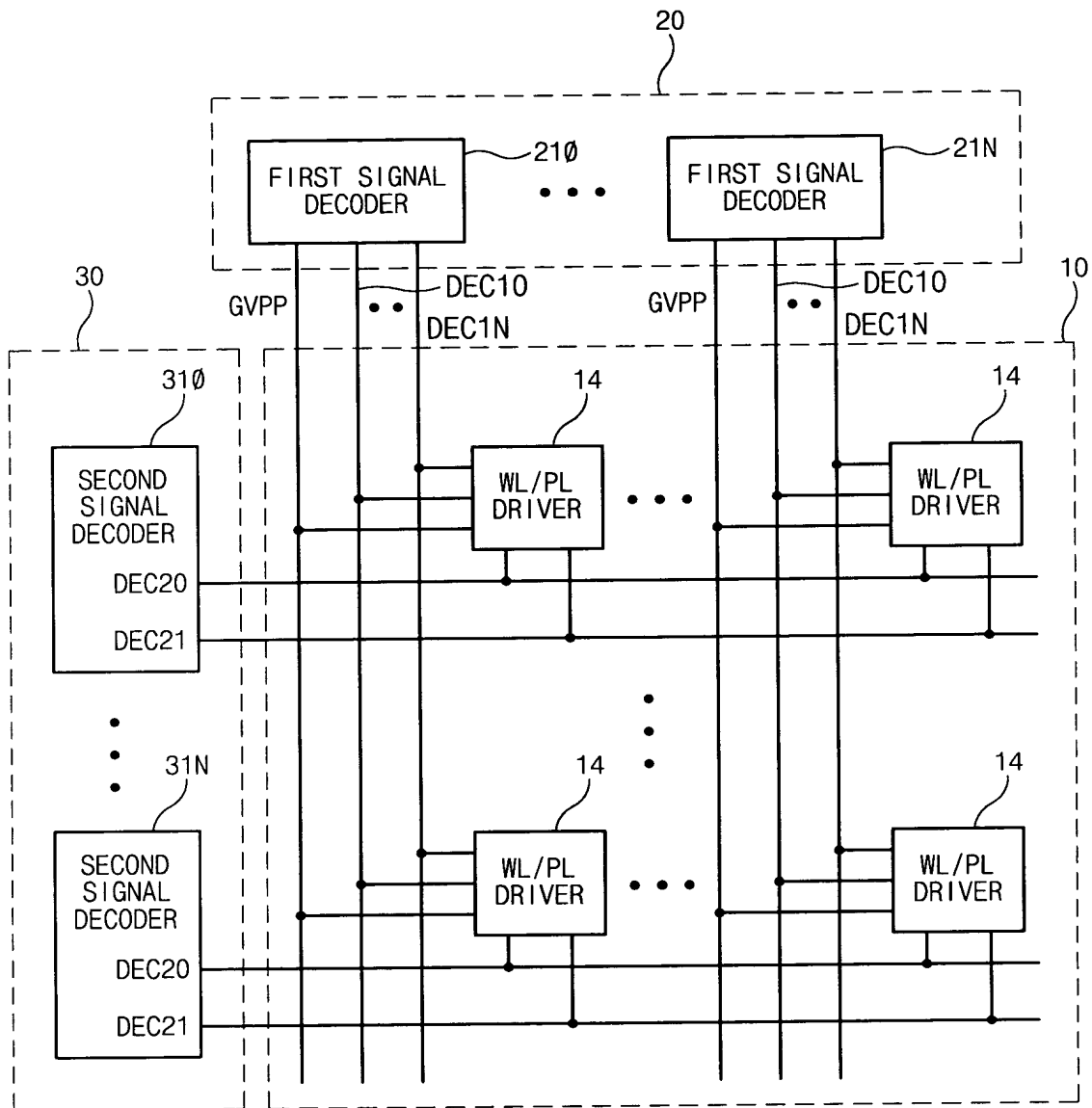


Fig.12

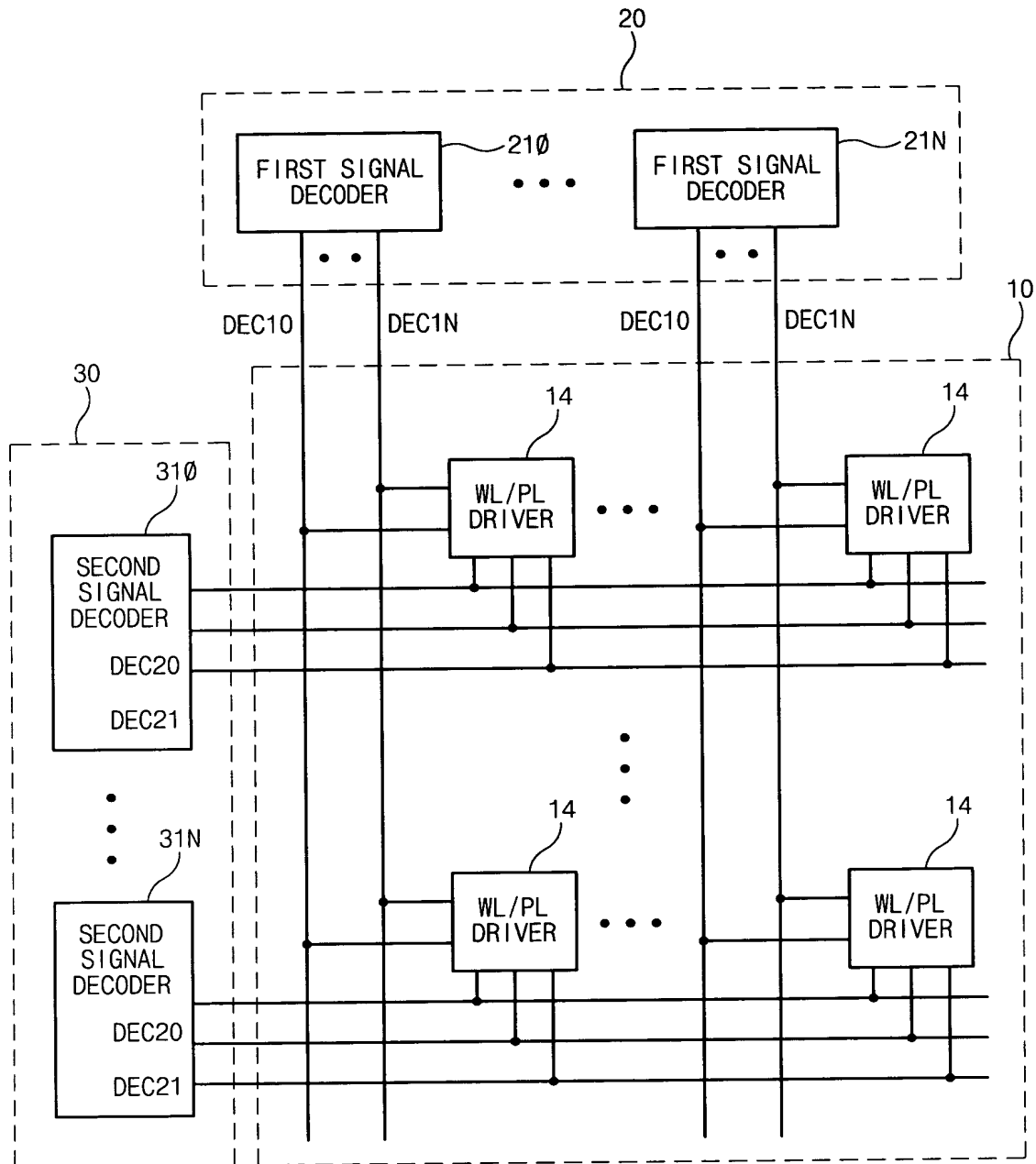


Fig.13

Hee Bok KANG
"Nonvolatile Ferroelectric Memory Device"
Attorney Docket No.: 40296-0009

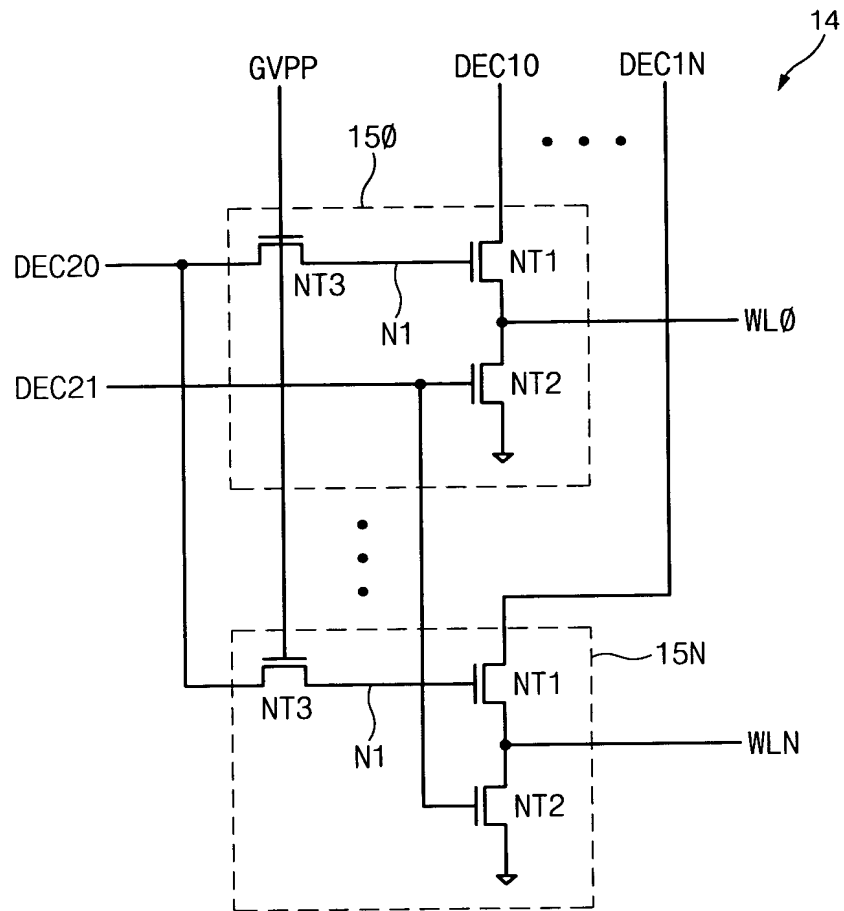


Fig.14

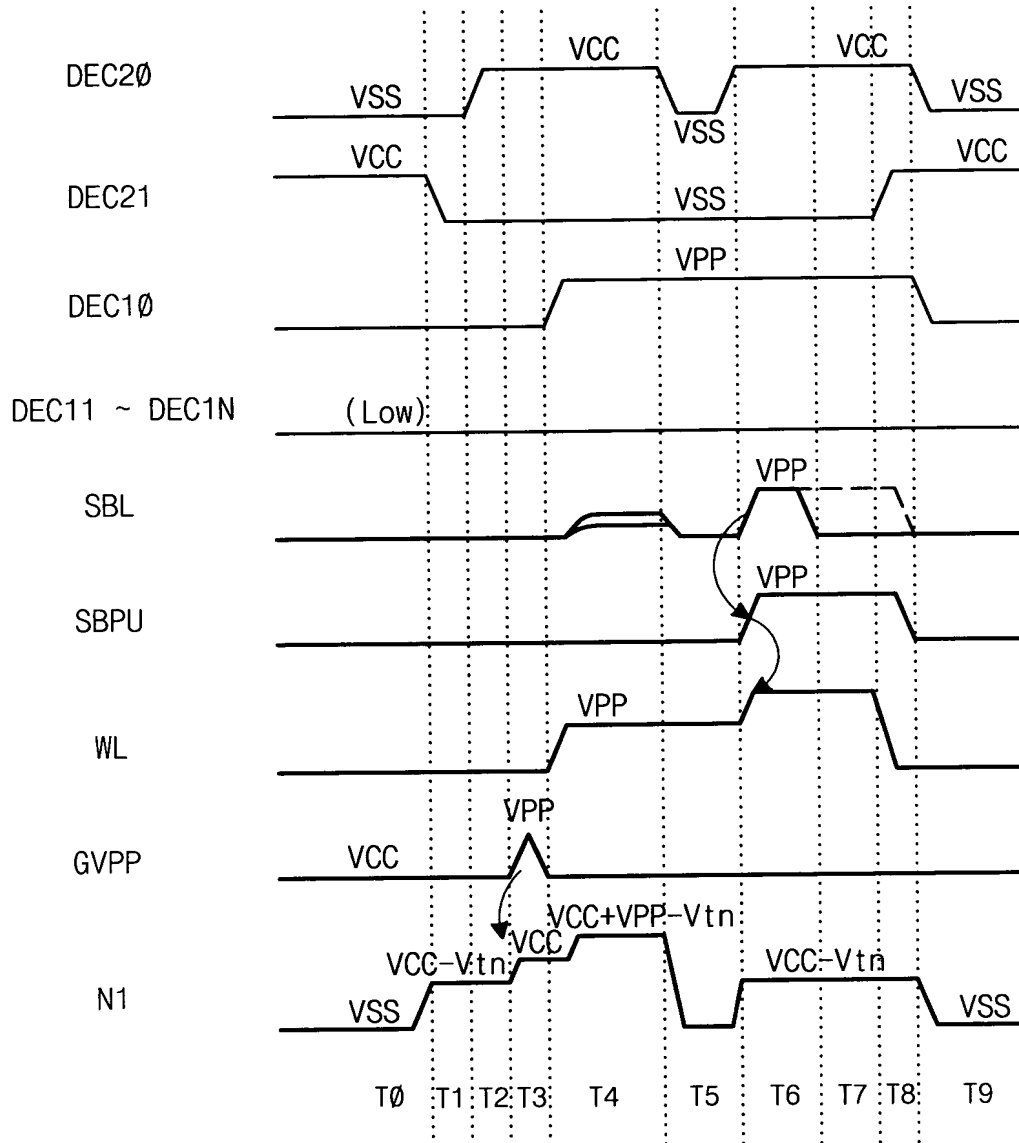


Fig.15

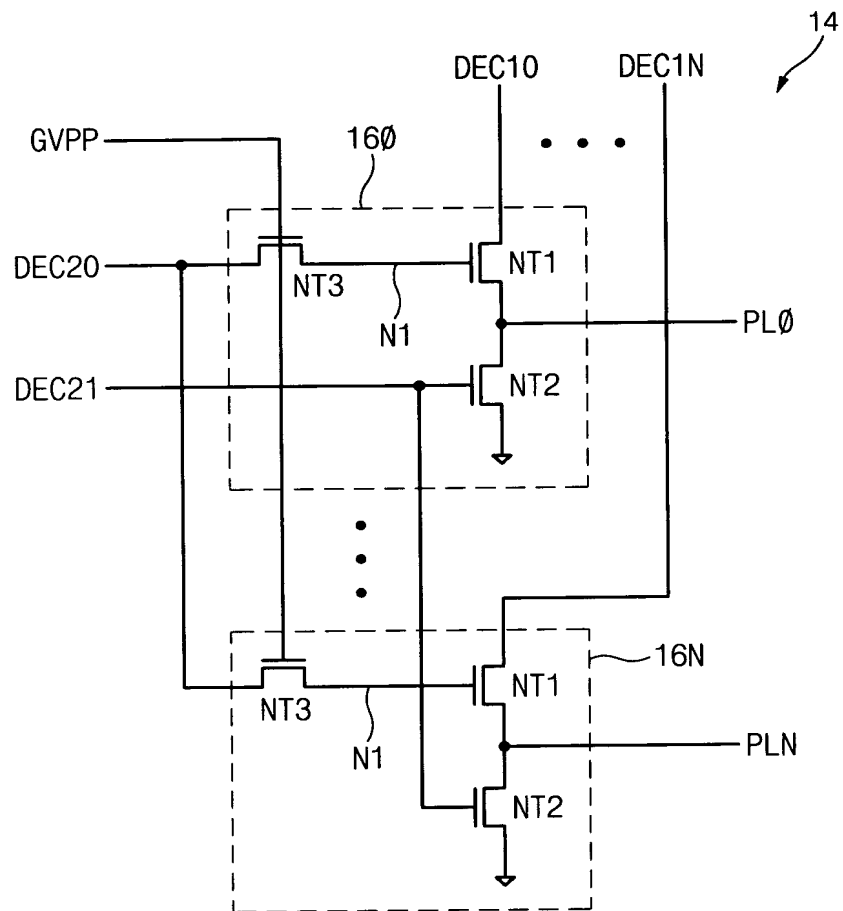


Fig.16

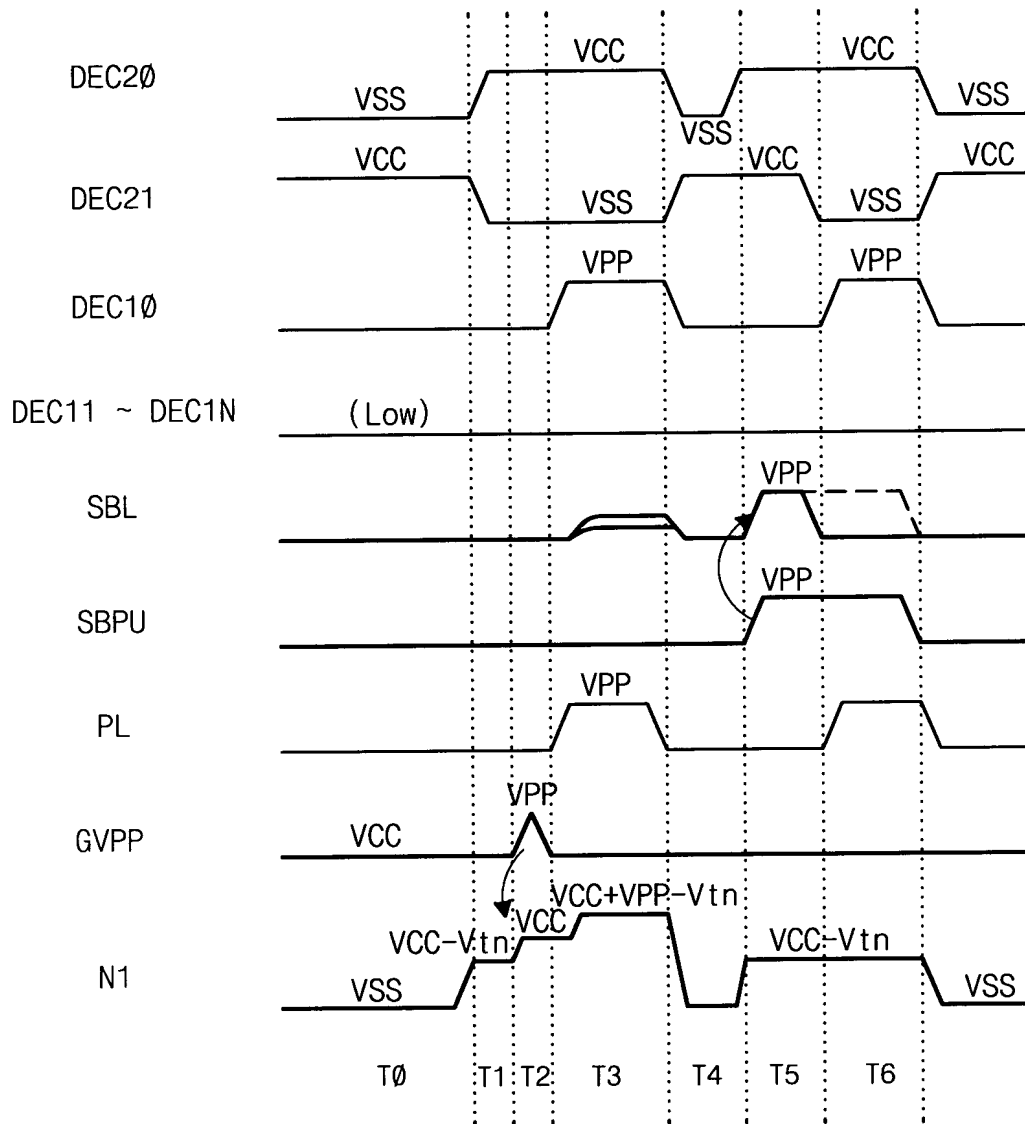


Fig.17

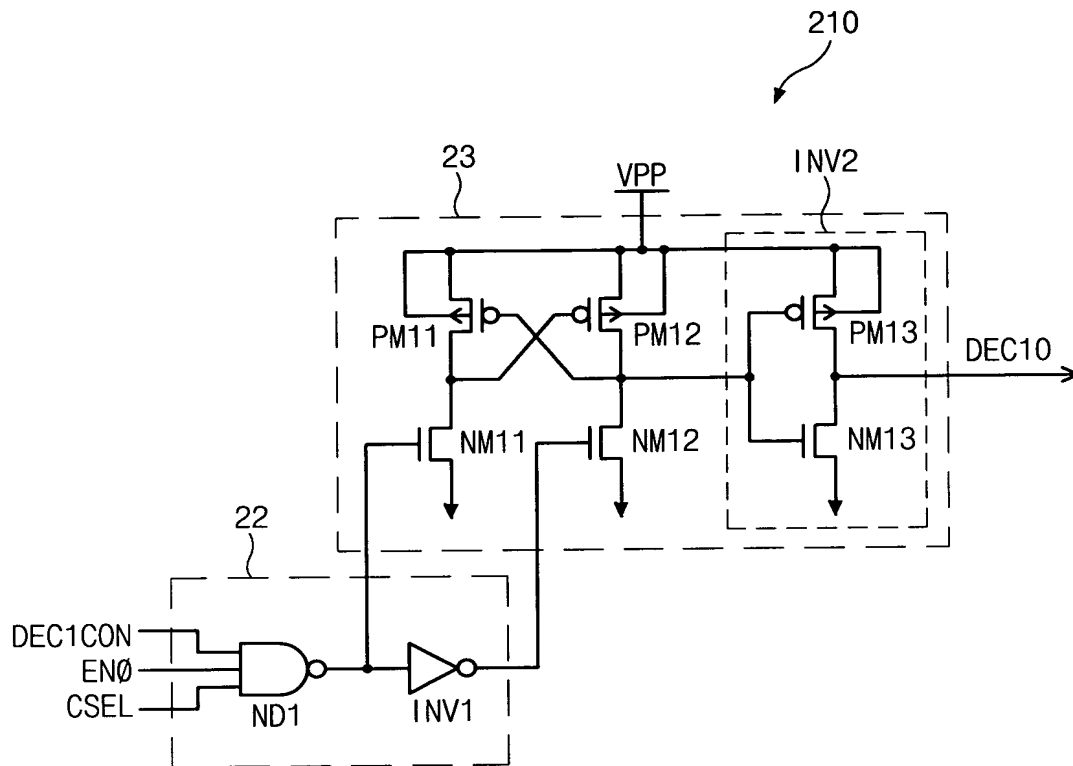


Fig.18

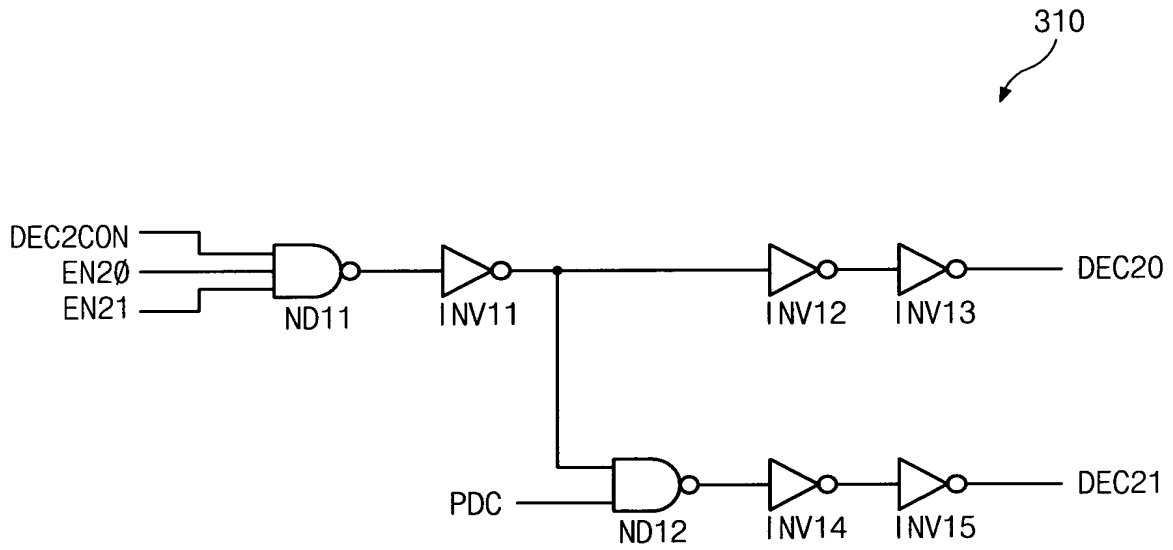


Fig.19

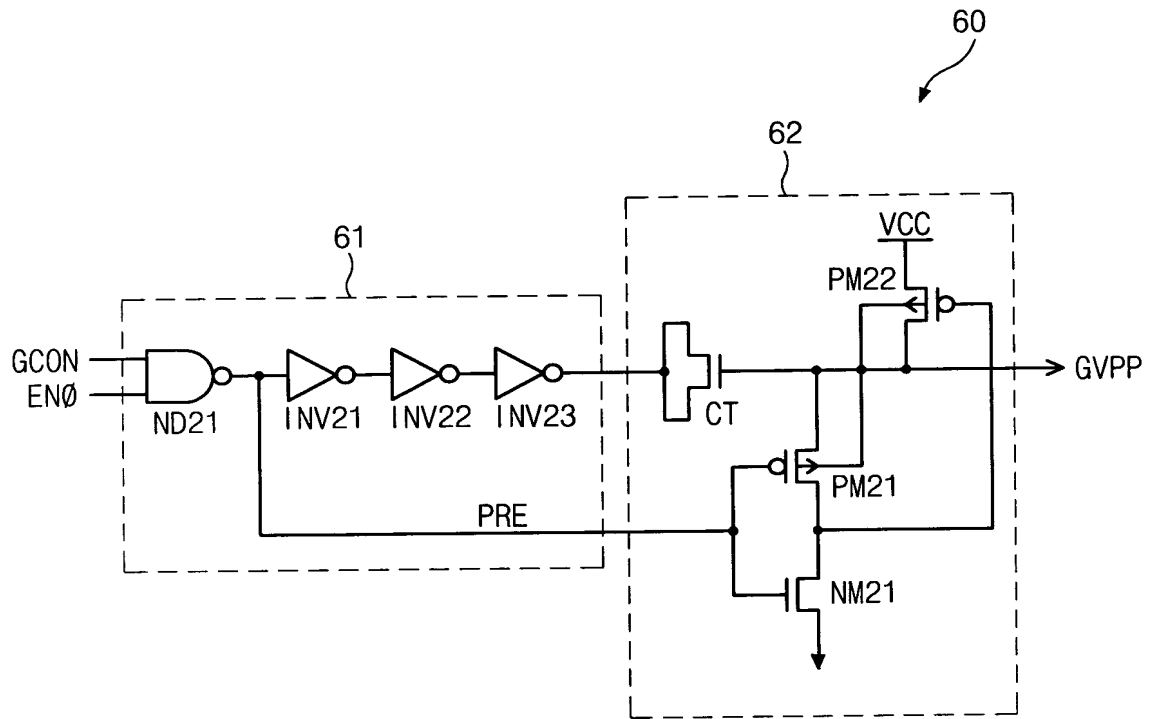


Fig.20

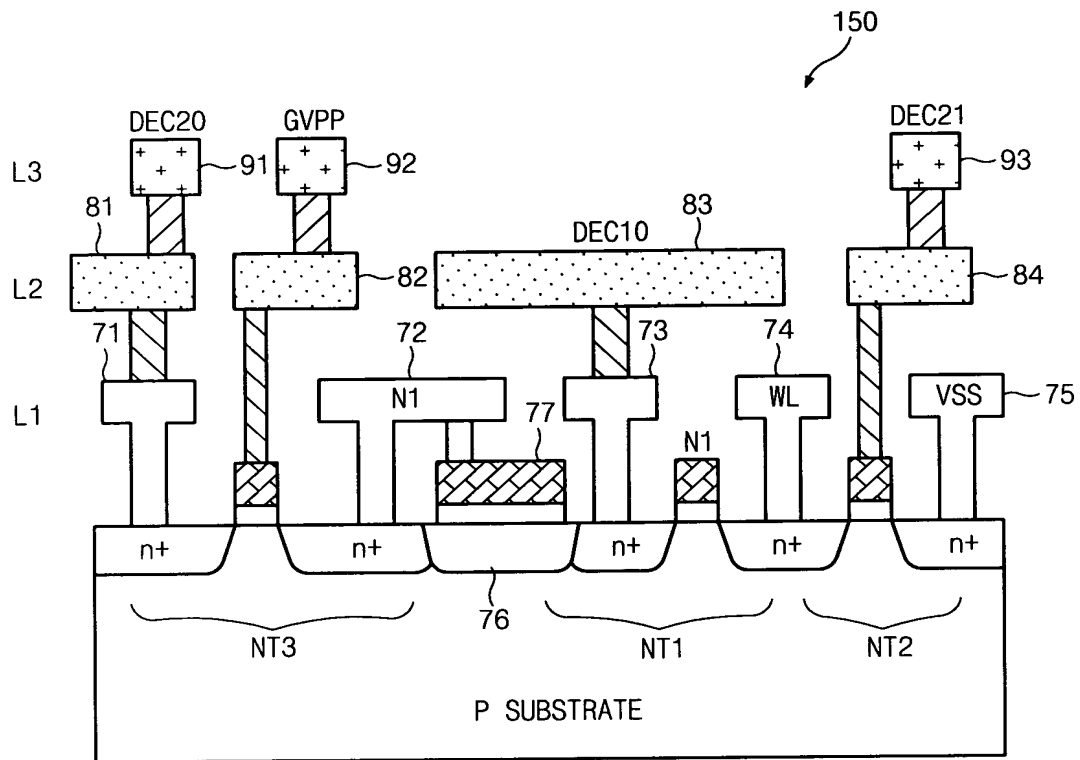


Fig.21

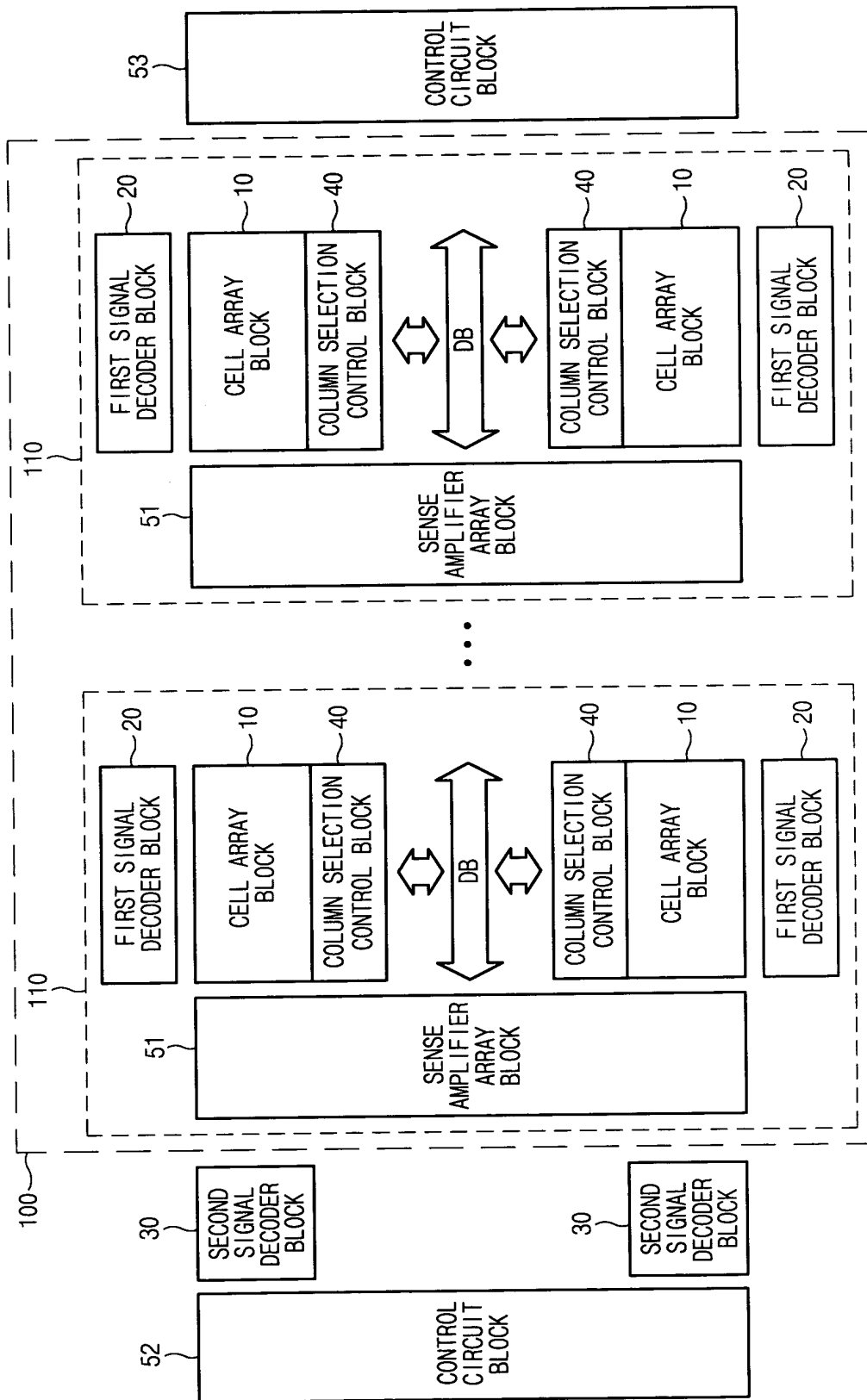


Fig.22

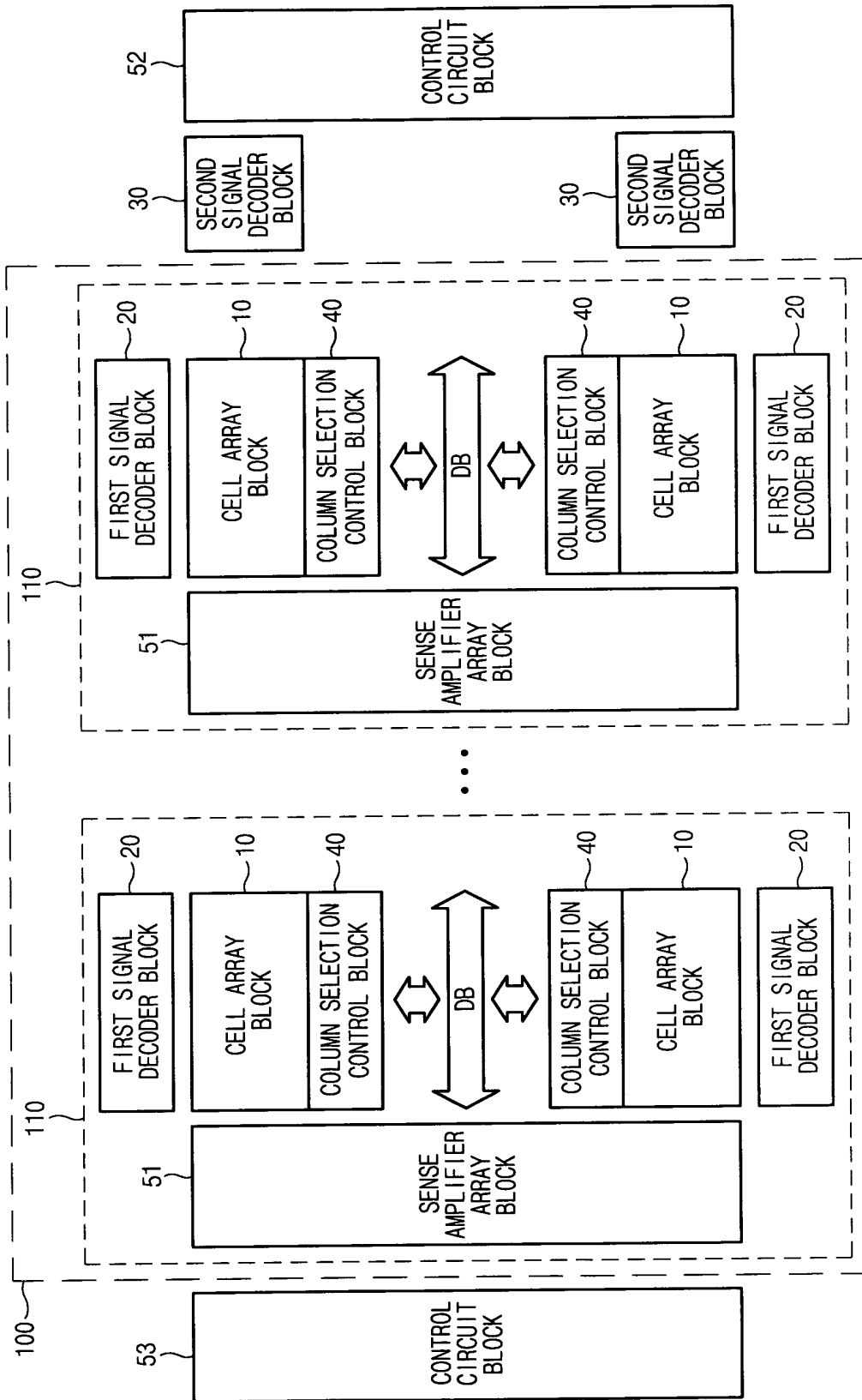


Fig.23

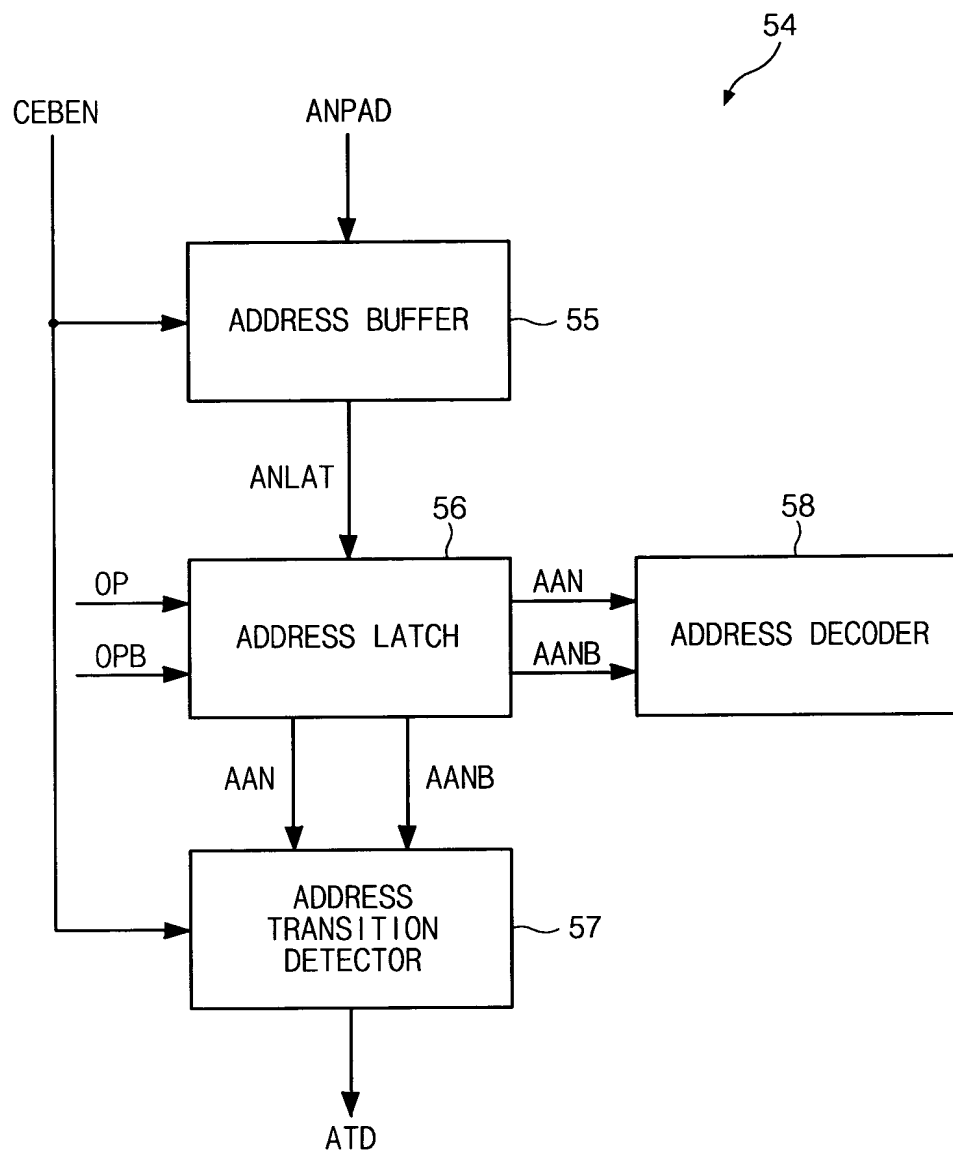


Fig.24

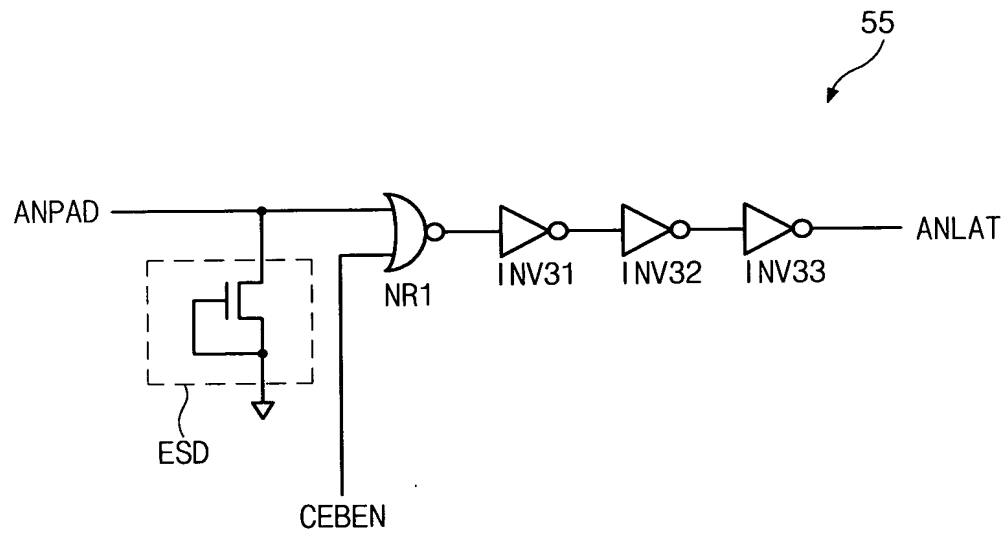


Fig.25

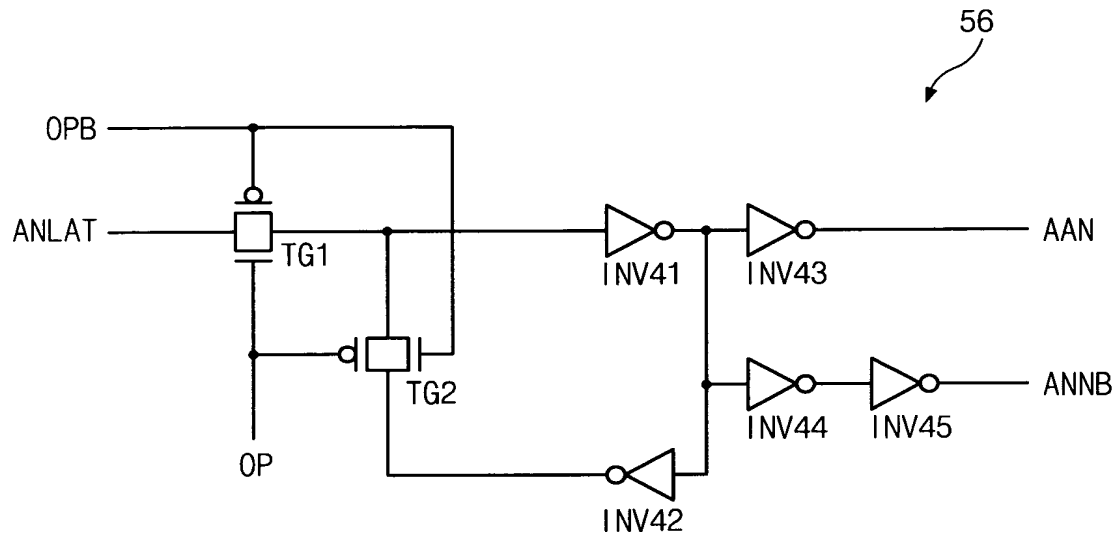
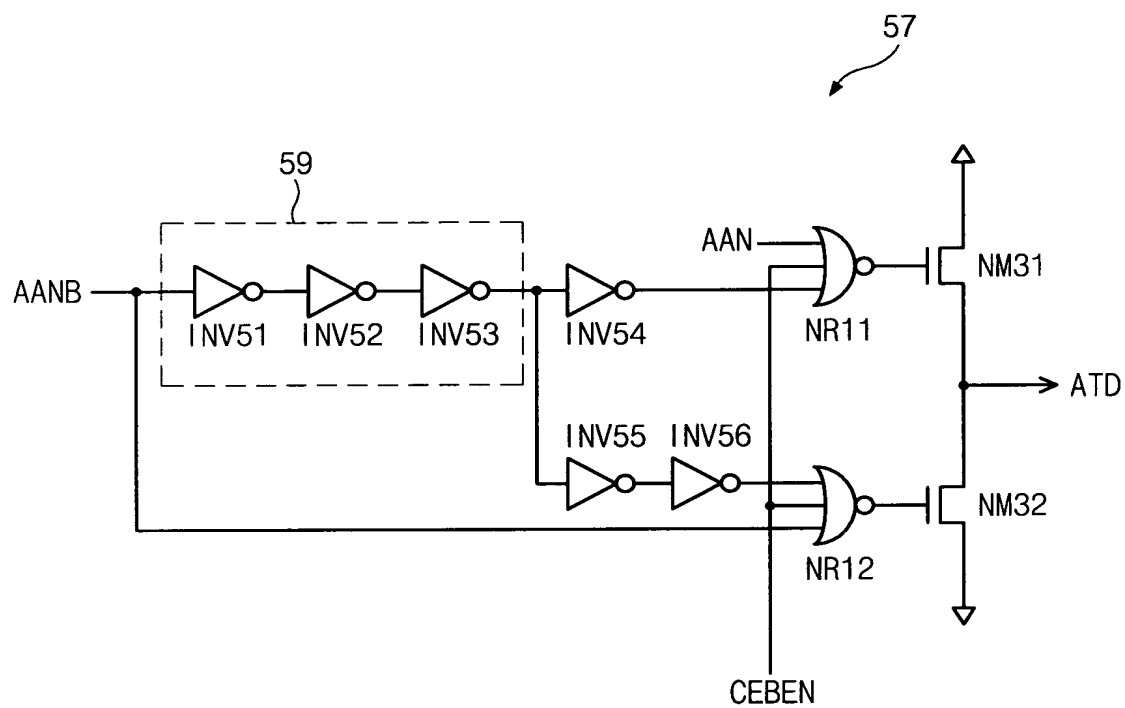


Fig.26

Fig.27



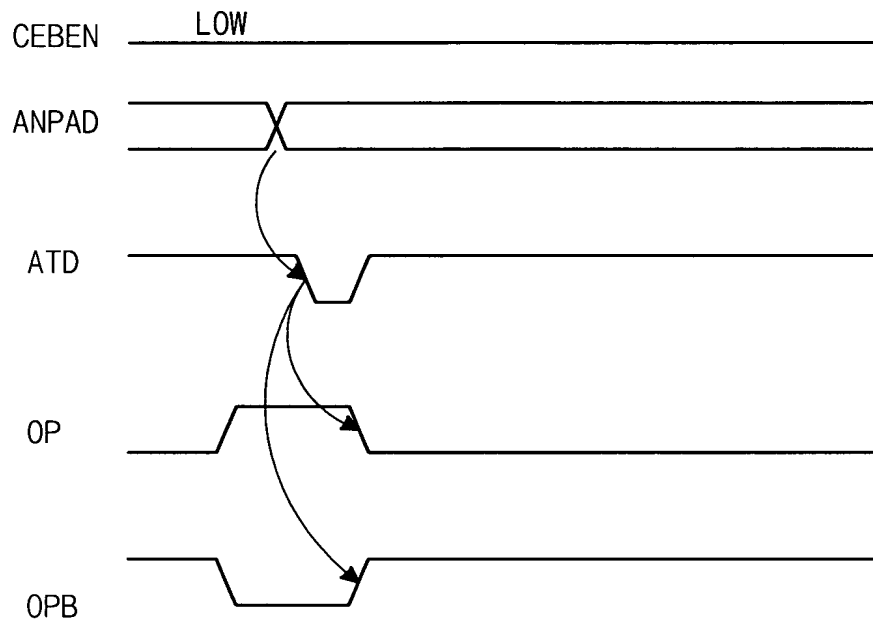


Fig.28